# **Surface Mount Schottky Power Rectifier**

# POWERMITE® Power Surface Mount Package

The Schottky Powermite employs the Schottky Barrier principle with a barrier metal and epitaxial construction that produces optimal forward voltage drop—reverse current tradeoff. The advanced packaging techniques provide for a highly efficient micro miniature, space saving surface mount Rectifier. With its unique heatsink design, the Powermite has the same thermal performance as the SMA while being 50% smaller in footprint area, and delivering one of the lowest height profiles, < 1.1 mm in the industry. Because of its small size, it is ideal for use in portable and battery powered products such as cellular and cordless phones, chargers, notebook computers, printers, PDAs and PCMCIA cards. Typical applications are ac/dc and dc—dc converters, reverse battery protection, and "Oring" of multiple supply voltages and any other application where performance and size are critical.

#### Features:

- Low I<sub>R</sub> Extends Battery Life
- Low Profile Maximum Height of 1.1 mm
- Small Footprint Footprint Area of 8.45 mm2
- 150°C Operating Junction Temperature
- Low Thermal Resistance with Direct Thermal Path of Die on Exposed Cathode Heat Sink

#### **Mechanical Characteristics:**

- Powermite is JEDEC Registered as D0–216AA
- Case: Molded Epoxy
- Epoxy Meets UL 94V-O at 1/8"
- Weight: 62 mg (approximately)
- Lead and Mounting Surface Temperature for Soldering Purposes.
   260°C Maximum for 10 Seconds

# **MAXIMUM RATINGS**

Please See the Table on the Following Page



ON Semiconductor™

http://onsemi.com

SCHOTTKY BARRIER
RECTIFIER
1.0 AMPERES
10 VOLTS



POWERMITE CASE 457 PLASTIC

**MARKING DIAGRAM** 



1E1 = Device Code M = Date Code

#### **ORDERING INFORMATION**

Device	Package	Shipping	
MBRM110ET1	POWERMITE	3,000/Tape & Reel	
MBRM110ET3	POWERMITE	12,000/Tape & Reel	

#### **MAXIMUM RATINGS**

Rating	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	10	V
Average Rectified Forward Current (T <sub>L</sub> = 100°C)	lo	1.0	А
Non-Repetitive Peak Surge Current (Non-Repetitive peak surge current, halfwave, single phase, 60 Hz)	I <sub>FSM</sub>	50	A
Storage Temperature	T <sub>stg</sub>	-55 to +150	°C
Operating Junction Temperature	TJ	-55 to +150	°C
Voltage Rate of Change (Rated V <sub>R</sub> , T <sub>J</sub> = 25°C)	dv/dt	10,000	V/µs

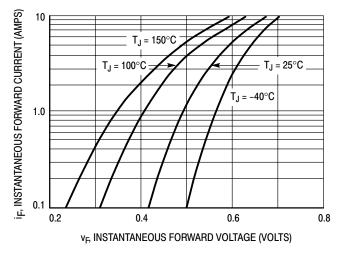
# THERMAL CHARACTERISTICS

Thermal Resistance – Junction–to–Lead (Anode) (Note 1)	$R_{til}$	35	°C/W
Thermal Resistance – Junction–to–Tab (Cathode) (Note 1)	R <sub>tjtab</sub>	23	
Thermal Resistance – Junction–to–Ambient (Note 1)	Ř <sub>tja</sub>	277	

# **ELECTRICAL CHARACTERISTICS**

Maximum Instantaneous Forward Voltage (Note 2)	V <sub>F</sub>	T <sub>J</sub> = 25°C	T <sub>J</sub> = 100°C	V
$(I_F = 0.1 \text{ A})$ $(I_F = 1.0 \text{ A})$ $(I_F = 2.0 \text{ A})$		0.455 0.530 0.595	0.360 0.455 0.540	
Maximum Instantaneous Reverse Current (Note 2)	I <sub>R</sub>	T <sub>J</sub> = 25°C	T <sub>J</sub> = 100°C	μΑ
$(V_R = 5.0 \text{ V})$ $(V_R = 10 \text{ V})$		0.5 1.0	300 500	

Mounted with minimum recommended pad size, PC Board FR4, See Figures 8 and 9.
 Pulse Test: Pulse Width ≤ 250 μs, Duty Cycle ≤ 2%.



T<sub>J</sub> =  $150^{\circ}$ C

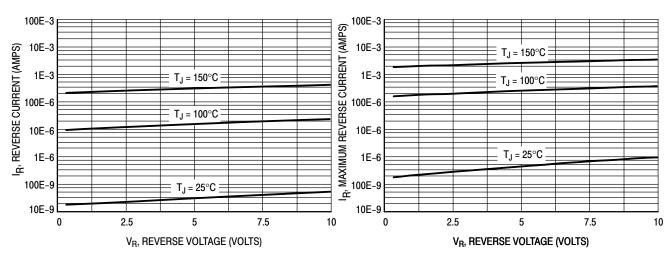
T<sub>J</sub> =  $150^{\circ}$ C

T<sub>J</sub> =  $25^{\circ}$ C

V<sub>E</sub> MAXIMUM INSTANTANEOUS FORWARD VOLTAGE (VOLTS)

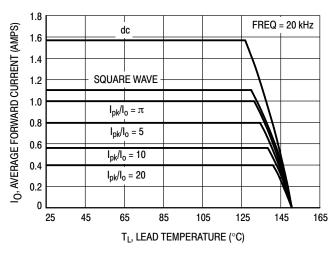
Figure 1. Typical Forward Voltage

Figure 2. Maximum Forward Voltage



**Figure 3. Typical Reverse Current** 

Figure 4. Maximum Reverse Current



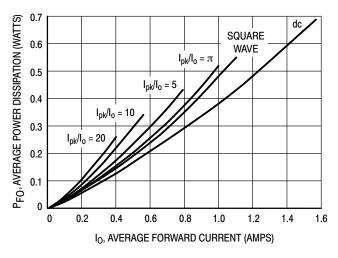


Figure 5. Current Derating

Figure 6. Forward Power Dissipation

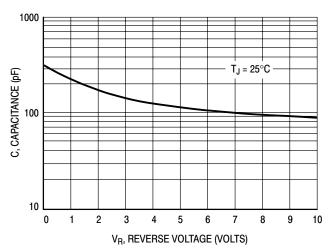


Figure 7. Capacitance

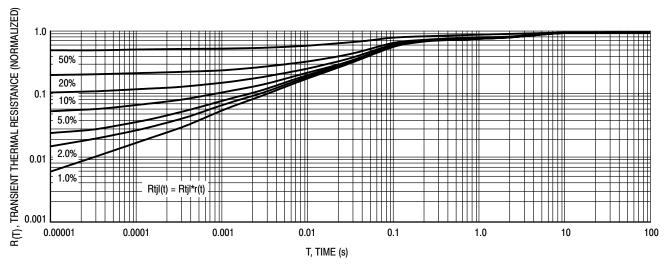


Figure 8. Thermal Response Junction to Lead

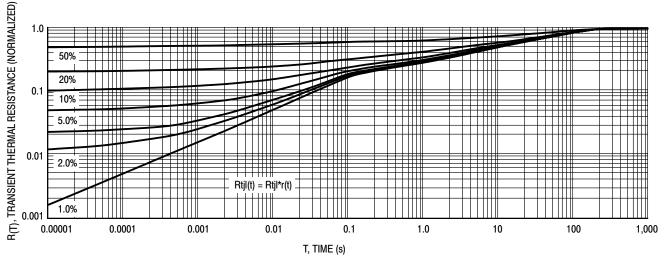
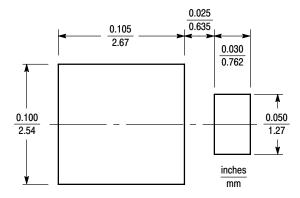


Figure 9. Thermal Response Junction to Ambient

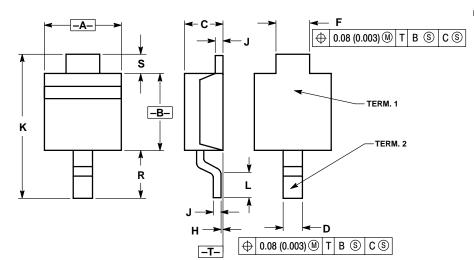


**Minimum Recommended Footprint** 

# **PACKAGE DIMENSIONS**

#### **POWERMITE**

PLASTIC PACKAGE CASE 457-04 ISSUE D



- NOTES:
  1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  2. CONTROLLING DIMENSION: MILLIMETER.
  3. DIMENSION A DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH, PROTRUSIONS OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.

	MILLIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
Α	1.75	2.05	0.069	0.081
В	1.75	2.18	0.069	0.086
С	0.85	1.15	0.033	0.045
D	0.40	0.69	0.016	0.027
F	0.70	1.00	0.028	0.039
Н	-0.05	+0.10	-0.002	+0.004
J	0.10	0.25	0.004	0.010
K	3.60	3.90	0.142	0.154
L	0.50	0.80	0.020	0.031
R	1.20	1.50	0.047	0.059
S	0.50 REF		0.019 REF	



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